

SANYO Semiconductors DATA SHEET

N-Channel Silicon MOSFET

ECH8616 — General-Purpose Switching Device Applications

Features

- · Ultrahigh-speed switching.
- · 4V drive.
- · Composite type, facilitating high-density mounting.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		60	٧
Gate-to-Source Voltage	VGSS		±20	٧
Drain Current (DC)	ΙD		3	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	20	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (900mm ² X0.8mm) 1unit	1.3	W
Total Dissipation	PT	Mounted on a ceramic board (900mm ² X0.8mm)	1.5	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =1mA, V _G S=0	60			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =60V, V _{GS} =0			1	μΑ
Gate-to-Source Leakage Current	IGSS	VGS=±16V, VDS=0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =10V, I _D =1mA	1.2		2.6	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =1.5A	2.2	3.8		S
Static Drain-to-Source On-State Resistance	RDS(on)1	ID=1.5A, VGS=10V		70	93	mΩ
	R _{DS} (on)2	I _D =0.5A, V _G S=4V		92	133	mΩ
Input Capacitance	Ciss	V _{DS} =20V, f=1MHz		560		pF
Output Capacitance	Coss	V _{DS} =20V, f=1MHz		60		pF
Reverse Transfer Capacitance	Crss	V _{DS} =20V, f=1MHz		41		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		11		ns
Rise Time	tr	See specified Test Circuit.		11		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		61		ns
Fall Time	tf	See specified Test Circuit.		32		ns

Marking: FJ Continued on next page.

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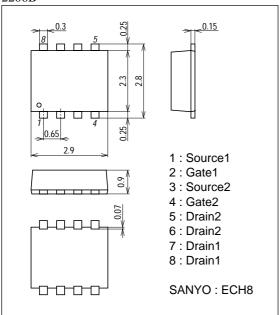
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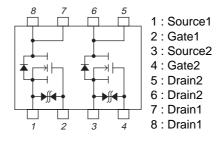
Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Total Gate Charge	Qg	V _{DS} =30V, V _{GS} =10V, I _D =3A		12.8		nC
Gate-to-Source Charge	Qgs	V _{DS} =30V, V _{GS} =10V, I _D =3A		2.1		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =30V, V _{GS} =10V, I _D =3A		2.7		nC
Diode Forward Voltage	VSD	IS=3A, VGS=0		0.81	1.2	V

Package Dimensions

unit : mm 2206B

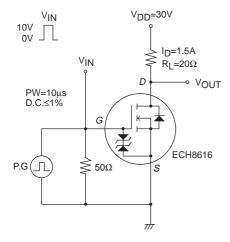


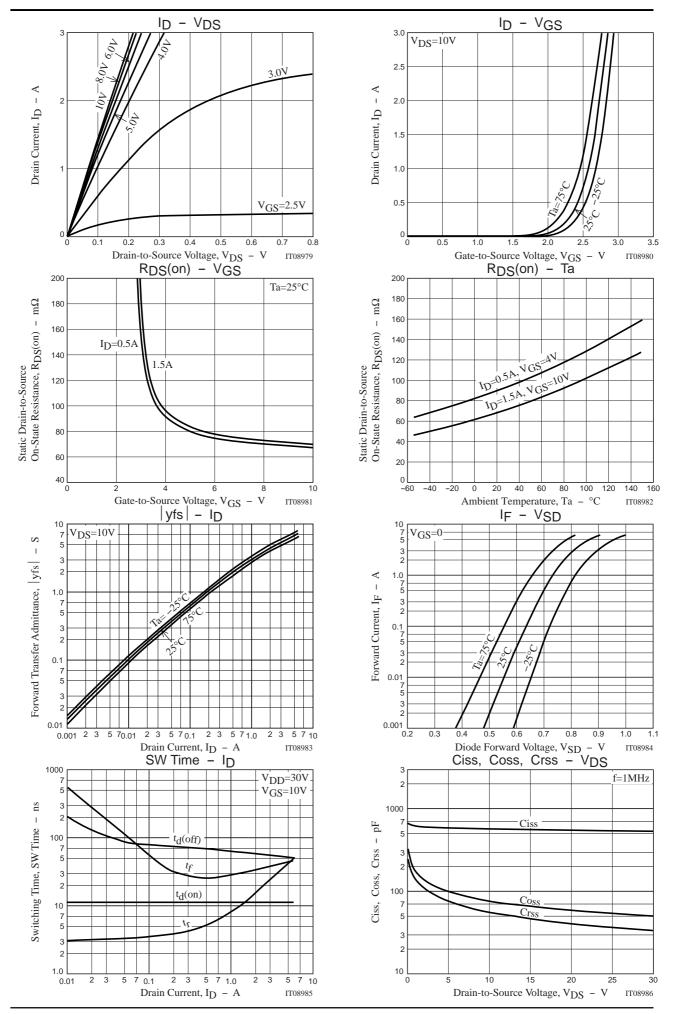
Electrical Connection



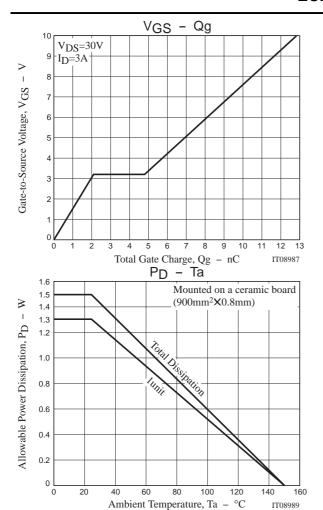
Top view

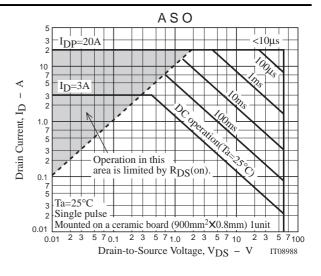
Switching Time Test Circuit





ECH8616





Note on usage: Since the ECH8616 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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